## NSN 5962-01-333-3430

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-333-3430

View Online at https://aerobasegroup.com/nsn/5962-01-333-3430
Overall Height:
Between 0.357 inches and 0.432 inches
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
350.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
60.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Eprom
Memory Capacity:

**Test Data Document:** 

 $96906\text{-mil-std-}883 \text{ standard (includes industry or association standards, \ individual manufactureer standards, \ etc.)}.$ 

**Terminal Type And Quantity:** 

28 printed circuit

Unknown

## NSN 5962-01-333-3430

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0